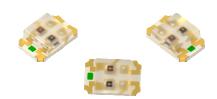


APHBM2012LQBDSURKC

2.0 x 1.25 mm SMD Chip LED Lamp



DESCRIPTIONS

- The Blue source color devices are made with InGaN Light Emitting Diode
- The Hyper Red source color devices are made with AlGaInP on GaAs substrate Light Emitting Diode
- Electrostatic discharge and power surge could damage the LEDs
- . It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs
- · All devices, equipments and machineries must be electrically grounded

FEATURES

- 2.0 mm x 1.25 mm SMD LED, 0.45 mm max. thickness
- Low power consumption
- · Wide viewing angle
- · Ideal for backlight and indicator
- · Package: 2000 pcs / reel
- Moisture sensitivity level: 3
- Halogen-free
- · RoHS compliant

APPLICATIONS

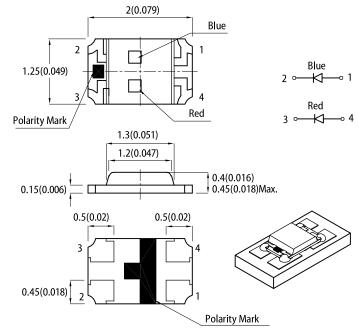
- Backlight
- · Status indicator
- · Home and smart appliances
- Wearable and portable devices
- · Healthcare applications

ATTENTION

Observe precautions for handling electrostatic discharge sensitive devices

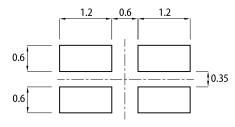


PACKAGE DIMENSIONS



RECOMMENDED SOLDERING PATTERN

(units: mm; tolerance: ± 0.1)



- 17. All dimensions are in millimeters (inches).
 2. Tolerance is ±0.1(0.004") unless otherwise noted.
 3. The specifications, characteristics and technical data described in the datasheet are subject to
- 4. The device has a single mounting surface. The device must be mounted according to the specifications

SELECTION GUIDE

Part Number	Emitting Color	Lens Type	Iv (mcd) @ 2mA [2]		Viewing Angle [1]	
raitivambei	(Material)	Lens Type	Min.	Тур.	201/2	
APHBM2012LQBDSURKC -	■ Blue (InGaN)	Water Clear	6	12		
			*6	*12	4000	
	■ Hyper Red (AlGalnP)		15	30	120°	
			*6	*15		

Notes.

1. 61/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.

2. Luminous intensity / luminous flux: +/-15%.

* Luminous intensity value is traceable to CIE127-2007 standards.





ELECTRICAL / OPTICAL CHARACTERISTICS at T_A=25°C

Parameter	Symbol	Emitting Color	Value			l l m i é
rarameter			Min.	Тур.	Max.	Unit
Wavelength at Peak Emission I _F = 2mA	λ_{peak}	Blue Hyper Red	-	460 645	-	nm
Dominant Wavelength I _F = 2mA	λ _{dom} ^[1]	Blue Hyper Red	-	465 630	-	nm
Spectral Bandwidth at 50% Φ REL MAX I _F = 2mA	Δλ	Blue Hyper Red	-	25 28	-	nm
Capacitance	С	Blue Hyper Red	-	100 35	-	pF
Forward Voltage I _F = 2mA	V _F ^[2]	Blue Hyper Red	2.2 1.5	2.65 1.75	3.0 2.1	V
Reverse Current (V _R = 5V)	I _R	Blue Hyper Red	-	-	50 10	μΑ
Temperature Coefficient of λ_{peak} $I_F = 2mA$, $-10^{\circ}C \le T \le 85^{\circ}C$	TC_{\lambdapeak}	Blue Hyper Red	-	0.04 0.14	-	nm/°C
Temperature Coefficient of λ_{dom} I _F = 2mA, -10°C \leq T \leq 85°C	TC _{Adom}	Blue Hyper Red	-	0.03 0.05	-	nm/°C
Temperature Coefficient of V_F I_F = 2mA, -10°C \leq T \leq 85°C	TC _V	Blue Hyper Red	-	-3 -1.9	-	mV/°C

Notes:

ABSOLUTE MAXIMUM RATINGS at T_A=25°C

Dougnator	Ob. al	Val	11-14		
Parameter	Symbol	Blue	Hyper Red	Unit	
Power Dissipation	P_D	120	75	mW	
Reverse Voltage	V _R	5	5	V	
Junction Temperature	T _j	115	115	°C	
Operating Temperature	T _{op}	-40 to	°C		
Storage Temperature	T _{stg}	-40 to	°C		
DC Forward Current	I _F	30	30	mA	
Peak Forward Current	I _{FM} ^[1]	150	185	mA	
Electrostatic Discharge Threshold (HBM)	-	250	3000	V	
Thermal Resistance (Junction / Ambient)	R _{th JA} ^[2]	710	750	°C/W	
Thermal Resistance (Junction / Solder point)	R _{th JS} ^[2]	540	620	°C/W	

^{1.} The dominant wavelength (λd) above is the setup value of the sorting machine. (Tolerance $\lambda d:\pm 1$ nm.)

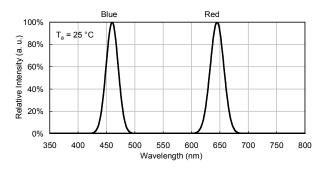
^{2.} Forward voltage: ±0.1V.
3. Wavelength value is traceable to CIE127-2007 standards.
4. Excess driving current and / or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

Notes:
1. 1/1/0 Duty Cycle, 0.1ms Pulse Width.
2. $R_{th,JA}$, $R_{th,JS}$ Results from mounting on PC board FR4 (pad size \geq 16 mm² per pad).
3. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.

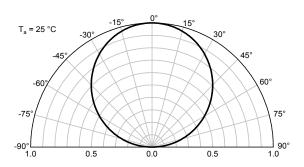


TECHNICAL DATA

RELATIVE INTENSITY vs. WAVELENGTH

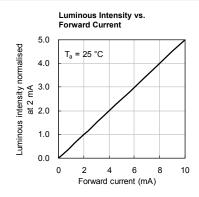


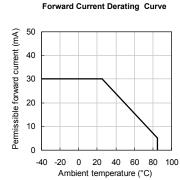
SPATIAL DISTRIBUTION

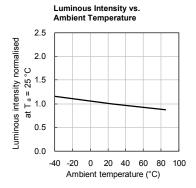


BLUE

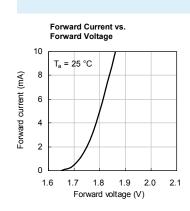
Forward Current vs. Forward Voltage 10 T_a = 25 °C 8 Forward current (mA) 6 4 2 0 2.0 2.2 2.4 2.6 2.8 3.0 3.2 Forward voltage (V)

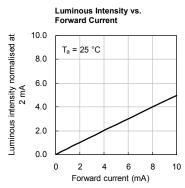


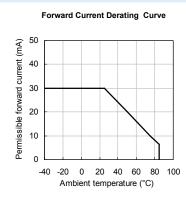


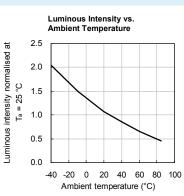


HYPER RED



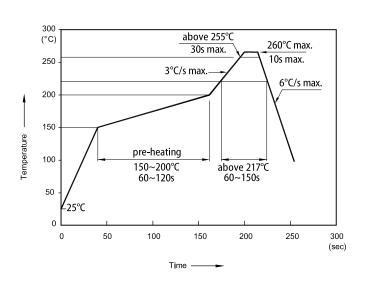




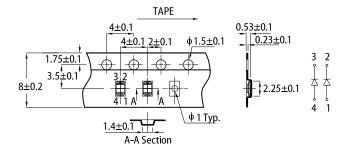


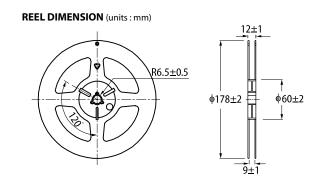


REFLOW SOLDERING PROFILE for LEAD-FREE SMD PROCESS



TAPE SPECIFICATIONS (units:mm)





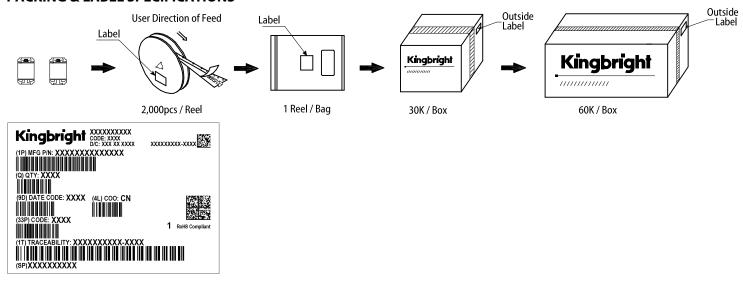
- Notes:

 1. Don't cause stress to the LEDs while it is exposed to high temperature.

 2. The maximum number of reflow soldering passes is 2 times.

 3. Reflow soldering is recommended. Other soldering methods are not recommended as they might cause damage to the product.

PACKING & LABEL SPECIFICATIONS



PRECAUTIONARY NOTES

- The information included in this document reflects representative usage scenarios and is intended for technical reference only
- The part number, type, and specifications mentioned in this document are subject to future change and improvement without notice. Before production usage customer should refer to the latest datasheet for the updated specifications.
- When using the products referenced in this document, please make sure the product is being operated within the environmental and electrical limits specified in the datasheet. If customer usage exceeds the specified limits, Kingbright will not be responsible for any subsequent issues.

 The information in this document applies to typical usage in consumer electronics applications. If customer's application has special reliability requirements or have life-threatening
- liabilities, such as automotive or medical usage, please consult with Kingbright representative for further assistance.
- The contents and information of this document may not be reproduced or re-transmitted without permission by Kingbright.
- All design applications should refer to Kingbright application notes available at https://www.Ki

